NSN 5962-01-126-8367

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
02-1252087-1 07397
Features Provided:
Static operation and 3-state output and high performance and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Control of the Control
Output Logic Form:
Metal oxide-semiconductor logic
Input Circuit Pattern:
15 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Memory Device Type:
Ram
Test Data Document:
34649-101059 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
18 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0